#### **TOSHIBA Photocoupler Photorelay**

# TLP797GA

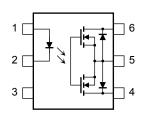
## Cordless Telephone PBX MODEM

The TOSHIBA TLP797GA consists of an aluminum gallium arsenide infrared emitting diode optically coupled to a photo-MOS FET in a six lead plastic DIP package (DIP6).

The TLP797GA is a bi-directional switch can replace mechanical relays in many applications.

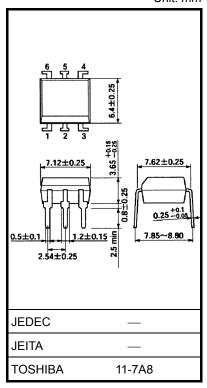
- 6 pin DIP (DIP6)
- 1-form-A
- Peak off-state voltage: 400 V (min)
- Trigger LED current: 3 mA (max)
- On-state current: 120 mA (max)
- On-state resistance:  $35 \Omega$  (max)
- Isolation voltage: 5000 Vrms (min)

#### Pin Configuration (top view)



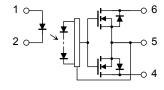
- 1: Anode
- 2: Cathode
- 3: N.C.
- 4: Drain D1
- 5: Source
- 6: Drain D2

#### Unit: mm



Weight: 0.4 g (typ.)

#### **Internal Circuit**



### **Absolute Maximum Ratings (Ta = 25°C)**

Characteristics			Symbol	Rating	Unit	
	Forward current		l <sub>F</sub>	50	mA	
	Forward current de (Ta ≥ 25°C)	erating	ΔI <sub>F</sub> /°C	-0.5	mA/°C	
LED	Peak forward curre (100 μs pulse, 100		I <sub>FP</sub> 1		Α	
	Reverse voltage		V <sub>R</sub>	5	V	
	Junction temperatu	ıre	Tj	125	°C	
	Off-state output ter	minal voltage	V <sub>OFF</sub>	400	V	
	On-state current	A connection		120		
		B connection	I <sub>ON</sub>	120	mA	
Detector		C connection		240		
Detector	On-state current derating	A connection		-1.2	<u> </u>	
		B connection	∆l <sub>ON</sub> /°C	-1.2	mA/°C	
	(Ta ≥ 25°C)	C connection		-2.4		
	Junction temperatu	ıre	Tj	125	°C	
Storage temperature range			T <sub>stg</sub>	-55 to 125	°C	
Operating temperature range			T <sub>opr</sub>	-40 to 85	°C	
Lead soldering temperature (10 s)			T <sub>sol</sub> 260		°C	
Isolation voltage (AC, 1 min., R.H. ≤ 60%) (Note)			BVS	5000	Vrms	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

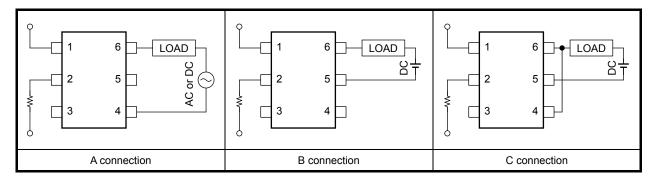
Note: Device considered a two-terminal device: Pins1, 2 and 3 shorted together, and pins 4, 5 and 6 shorted together.

#### **Recommended Operating Conditions**

Characteristics	Symbol	Min	Тур.	Max	Unit
Supply voltage	$V_{DD}$	_	_	320	V
Forward current	IF	5	7.5	25	mA
On-state current	I <sub>ON</sub>	_	_	120	mA
Operating temperature	T <sub>opr</sub>	-20	_	65	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

#### **Circuit Connections**



## **Individual Electrical Characteristics (Ta = 25°C)**

	Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
	Forward voltage	$V_{F}$	I <sub>F</sub> = 10 mA	1.0	1.15	1.3	V
LED	Reverse current	I <sub>R</sub>	V <sub>R</sub> = 5 V	_	_	10	μА
	Capacitance	C <sub>T</sub>	V = 0, $f = 1$ MHz	_	30	_	pF
Detector	Off-state current	l <sub>OFF</sub>	V <sub>OFF</sub> = 400 V	_	_	1	μΑ
Detector	Capacitance	C <sub>OFF</sub>	V = 0, $f = 1$ MHz		70		pF

## **Coupled Electrical Characteristics (Ta = 25°C)**

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Trigger LED current		I <sub>FT</sub>	I <sub>ON</sub> = 120 mA	_	1	3	mA
Load current limiting		I <sub>FC</sub>	I <sub>OFF</sub> = 100 μA	0.1	_	_	mA
	A connection		I <sub>ON</sub> = 120 mA, I <sub>F</sub> = 5 mA	_	17	35	Ω
On-state resistance	A connection	Pou	$I_{ON} = 20$ to 120 mA, $I_F = 5$ mA	_	20	40	
On-State resistance	B connection	R <sub>ON</sub>	I <sub>ON</sub> = 120 mA, I <sub>F</sub> = 5 mA	_	11	20	
	C connection		I <sub>ON</sub> = 240 mA, I <sub>F</sub> = 5 mA	_	6	_	

## **Isolation Characteristics (Ta = 25°C)**

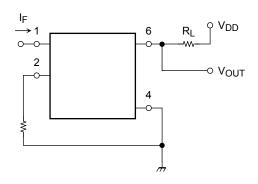
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance input to output	CS	V <sub>S</sub> = 0, f = 1 MHz	_	0.8	_	pF
Isolation resistance	R <sub>S</sub>	V <sub>S</sub> = 500 V, R.H. ≤ 60%	5 × 10 <sup>10</sup>	10 <sup>14</sup>	_	Ω
Isolation voltage	BVS	AC, 1 minute	5000	_	_	Vrms
		AC, 1 second (in oil)	_	10000	_	VIIIIS
		DC, 1 minute (in oil)	_	10000	_	Vdc

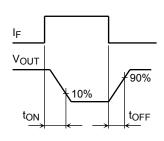
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# **Switching Characteristics (Ta = 25°C)**

Characteristics	Symbol	Test Condition		Min	Тур.	Max	Unit
Turn-on time	ton	$ \begin{aligned} R_L &= 200 \; \Omega \\ V_{DD} &= 20 \; V, \; I_F = 5 \; \text{mA} \end{aligned} $	(Note)		0.3	1	ms
Turn-off time	tOFF	$\begin{aligned} R_L &= 200~\Omega \\ V_{DD} &= 20~V,~I_F = 5~\text{mA} \end{aligned} $	(Note)		0.1	1	ms

Note: Switching time test circuit





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   In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as
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